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NXP Semiconductors/Freescale Semiconductor, Inc. TYN16X-600RT,127

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Datasheet of TYN16X-600RT,127 - IC SCR 16A 600V TO-220F

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**Product data sheet** 

### 1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ( $T_{i(max)} = 150$  °C).

### 2. Features and benefits

- High junction operating temperature capability
- · High thermal cycling performance
- High voltage capability
- Isolated package
- Planar passivated for voltage ruggedness and reliability
- Very high current surge capability

### 3. Applications

- Ignition circuits
- Motor control
- Protection circuits e.g. SMPS inrush current
- Voltage regulation

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DRM}$	repetitive peak off- state voltage		-	-	600	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	600	V
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 ^{\circ}\text{C}$ ; $t_p = 10 \text{ms}$ ; Fig. 4; Fig. 5	-	-	210	Α
		half sine wave; $T_{j(init)} = 25 ^{\circ}C$ ; $t_p = 8.3  ms$	-	-	231	Α
T <sub>j</sub>	junction temperature		-	-	150	°C
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>h</sub> ≤ 86 °C; <u>Fig. 1</u>	-	-	10.2	Α





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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>h</sub> ≤ 86 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	16	Α
Static characte	eristics		,			
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 ^{\circ}\text{C}; Fig. 7$	-	4.5	25	mA
Dynamic chara	acteristics					-
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; $T_j$ = 150 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit	300	-	-	V/µs

### 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	A <del>-                                   </del>
2	А	anode		G sym037
3	G	gate		,
mb	n.c.	mounting base; isolated		
			TO-220F (SOT186A)	

# 6. Ordering information

Table 3. Ordering information

Type number	Package							
	Name	Description	Version					
TYN16X-600RT	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A					

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		-3 ( )			
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage		-	600	V
$V_{RRM}$	repetitive peak reverse voltage		-	600	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>h</sub> ≤ 86 °C; <u>Fig. 1</u>	-	10.2	Α
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>h</sub> ≤ 86 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	16	Α

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Symbol	Parameter	Conditions	Min	Max	Unit
I <sub>TSM</sub>	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 10 \text{ ms}$ ; Fig. 4; Fig. 5	-	210	А
		half sine wave; $T_{j(init)} = 25 ^{\circ}C$ ; $t_p = 8.3  \text{ms}$	-	231	A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	220.5	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_T$ = 40 A; $I_G$ = 200 mA; $dI_G$ / $dt$ = 200 mA/ $\mu$ s	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	5	Α
$V_{RGM}$	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	20	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
T <sub>j</sub>	junction temperature		-	150	°C

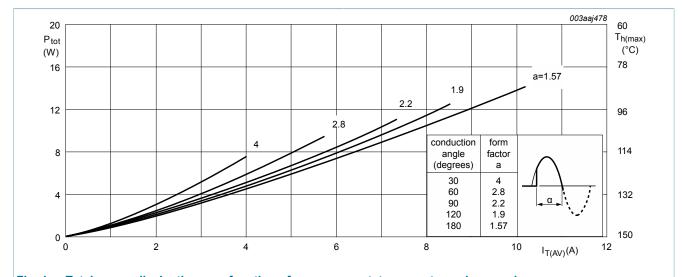


Fig. 1. Total power dissipation as a function of average on-state current; maximum values

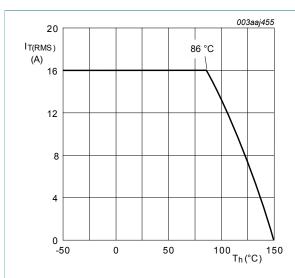
 $\mathbf{a} = \mathbf{form} \ \mathbf{factor} = \mathbf{I}_{T(RMS)} \, / \, \mathbf{I}_{T(AV)}$ 

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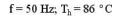
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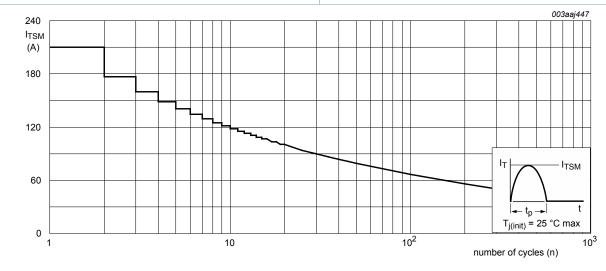


100 IT(RMS) 80 60 40 20 0 L 10<sup>-2</sup> 10<sup>-1</sup> surge duration (s)

RMS on-state current as a function of heatsink temperature; maximum values

Fig. 3. RMS on-state current as a function of surge duration; maximum values





Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

f = 50 Hz

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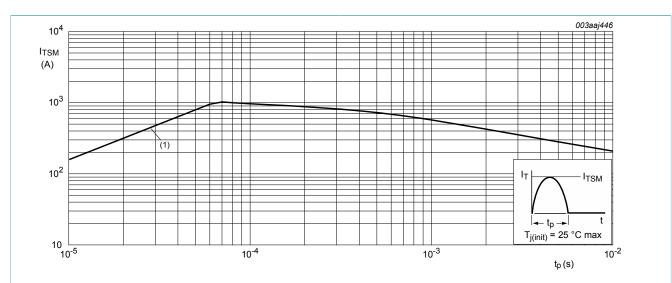
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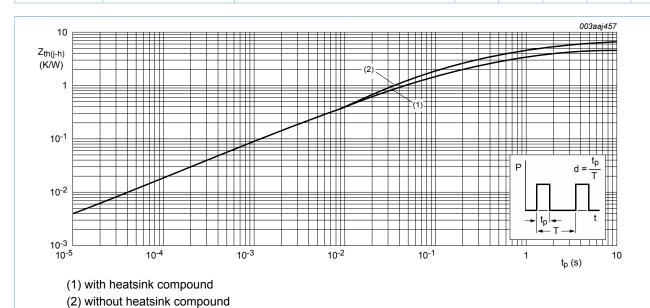
Non-repetitive peak on-state current as a function of pulse width for sinusoidal currents; maximum values  $t_{\rm p} \leq 10 \; {
m ms}; \, (1) \; {
m dI_T} \, / \; {
m dt \; limit}$ 

### Thermal characteristics

Table 5. Thermal characteristics

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100000							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-h)</sub>	thermal resistance	with heatsink compound; Fig. 6		-	-	4.5	K/W
	from junction to heatsink	without heatsink compound; Fig. 6		-	-	6.5	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air		-	55	-	K/W



Transient thermal impedance from junction to heatsink as a function of pulse width Fig. 6.



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### **Isolation characteristics**

#### Table 6. **Isolation characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>isol(RMS)</sub>	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz $\leq$ f $\leq$ 60 Hz; RH $\leq$ 65 %; $T_h = 25$ °C	-	-	2500	V
C <sub>isol</sub>	isolation capacitance	from anode to external heatsink; f = 1 MHz; T <sub>h</sub> = 25 °C	-	10	-	pF

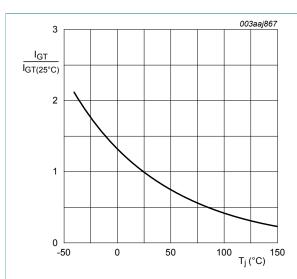
### 10. Characteristics

#### Table 7. **Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C}; Fig. 7$	-	4.5	25	mA
I <sub>L</sub>	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T_j = 25 ^{\circ}\text{C}; Fig. 8$	-	21	60	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	16	40	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 32 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
$V_{GT}$	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 11	-	0.7	1.3	V
		V <sub>D</sub> = 400 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 150 °C; Fig. 11	0.2	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 150 °C	-	0.2	1	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 150 °C	-	0.2	1	mA
Dynamic cl	haracteristics		l			
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; $T_j$ = 150 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit	300	-	-	V/µs

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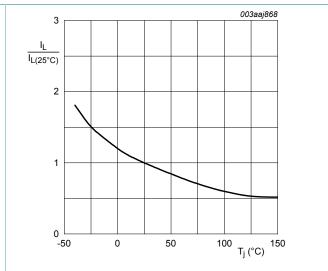
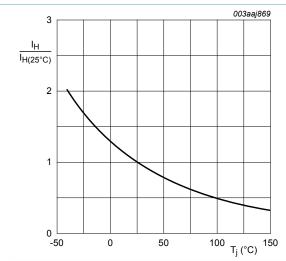


Fig. 7. Normalized gate trigger current as a function of junction temperature

Fig. 8. Normalized latching current as a function of junction temperature



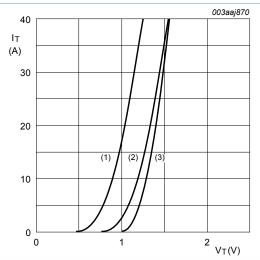


Fig. 9. Normalized holding current as a function of junction temperature

 $V_o$  = 1.0336 V;  $R_s$  = 0.0141 Ω (1)  $T_j$  = 150 °C; typical values (2)  $T_j$  = 150 °C; maximum values (3)  $T_i$  = 25 °C; maximum values

Fig. 10. On-state current as a function of on-state voltage



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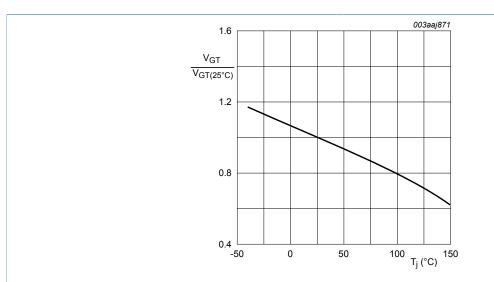


Fig. 11. Normalized gate trigger voltage as a function of junction temperature



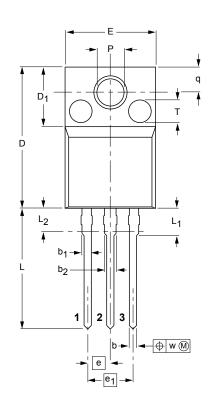
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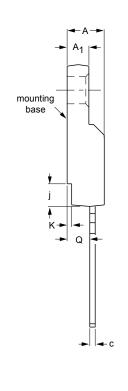
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### 11. Package outline

Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 'full pack'

SOT186A





0 5 10 mm Luuruuluuruul scale

#### DIMENSIONS (mm are the original dimensions)

UNI	ГА	A <sub>1</sub>	b	b <sub>1</sub>	b <sub>2</sub>	С	D	D <sub>1</sub>	E	е	e <sub>1</sub>	j	к	L	L <sub>1</sub>	L <sub>2</sub> <sup>(1)</sup> max.	Р	Q	q	T <sup>(2)</sup>	w
mn	4.6 4.0	2.9 2.5	0.9 0.7	1.1 0.9	1.4 1.0	0.7 0.4	15.8 15.2	6.5 6.3	10.3 9.7	2.54	5.08	2.7 1.7	0.6 0.4	14.4 13.5	3.30 2.79	3	3.2 3.0	2.6 2.3	3.0 2.6	2.5	0.4

#### Notes

- 1. Terminal dimensions within this zone are uncontrolled.
- 2. Both recesses are # 2.5 × 0.8 max. depth

OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT186A		3-lead TO-220F			<del>-02-04-09</del> 06-02-14

Fig. 12. Package outline TO-220F (SOT186A)

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